

IXTH52N65X

Request a Quote

IXTH52N65X Information

	Part Number	IXTH52N65X	
	Manufacturer	IXYS	
www.helsener.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
1	Description	MOSFET N-CH 650V 52A TO-247	
-11	Package	TO-247-3	
1.		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXTH52N65X Specifications

Manufacturer Part Number	IXTH52N65X
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	52A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	113nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4350pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	660W (Tc)
Rds On (Max) @ Id, Vgs	68 mOhm @ 26A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247 (IXTH)
Package / Case	TO-247-3
	Report errors?

IXTH52N65X Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTH52N65X Payment Methods



IXTH52N65X Shipping Methods



If you have any question about IXTH52N65X, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com